

Energy-Aware Computing

Lecture 11: Leakage power

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Outline

- Sources of leakage power
- Circuit level techniques
- Cache leakage reduction
 - Decay cache
 - Drowsy cache

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Sources of leakage power

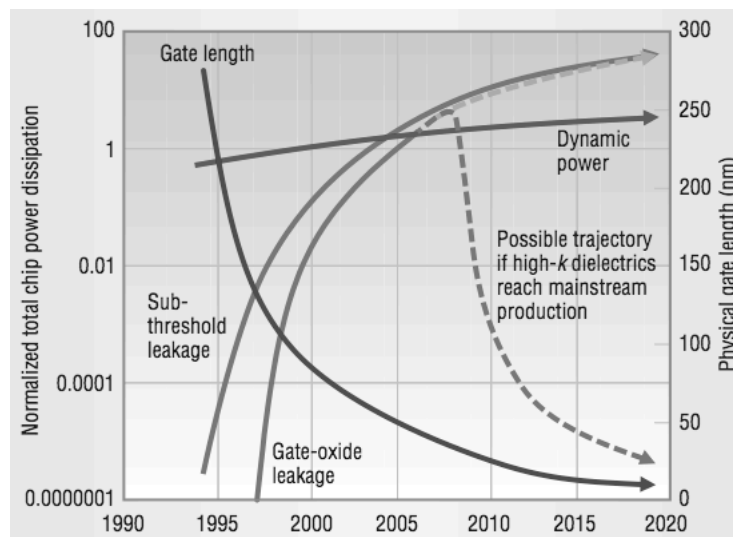
Remember, Power = current x Voltage

- Gate oxide leakage current
 - Current flows through gate oxide
- Subthreshold leakage current
 - Transistor does not turn off fully
- A few more leakage currents
 - Not as important as the above

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Total power dissipation



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Gate oxide leakage

$$I_{ox} = K_2 W \left(\frac{V}{T_{ox}} \right)^2 e^{-\sigma_{ox} V}$$

- Parameters
 - T_{ox} - oxide thickness
- New dielectric materials greatly reduce gate oxide leakage so it will not be a problem

Subthreshold leakage

$$I_{sub} = K_1 W e^{(V_{gs} - V_{th} - V_{gs} / n) / V_{\theta}} (1 - e^{-V_{ds} / V_{\theta}})$$

- Terms:
 - V_{θ} - thermal voltage increases linearly with temp
 - W - transistor width
 - V_{th} - threshold voltage
- How to control
 - Increase V_{th}
 - Performance, dynamic power (cannot reduce V) loss
 - Turn off voltage ($V_{ds}=0$)
 - State loss
 - Decrease W
 - Performance loss

Leakage power for architects

- Butts and Sohi (MICRO'00) propose the following equation for leakage
 - Subthreshold only $P_{leak} = VNk_{design} \hat{I}_{leak}$
- What can we do?
 - Reduce voltage
 - Reduce number of devices
 - Either use fewer on chip or shut off some
 - Circuit design style (k_{design})
 - Slower, less leaky transistors (I_{leak})

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Low-level techniques

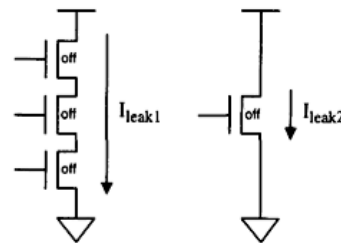
- MTCMOS - multi-threshold
 - Use high V_{th} for non-critical path
- Reverse back-bias
 - Control the 4th transistor terminal - body
 - Effectively increases the threshold voltage
 - Increases circuit size
- Stacking effect
 - Gated V_{dd}/V_{ss}

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Stacking effect

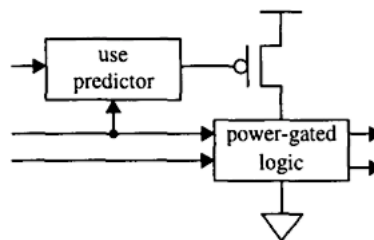
- Leakage is reduced in stacks of transistors
 - When more than 1 are off
 - Can be an order of magnitude better
 - Even better if one has high V_T
- Rationale
 - Drain-source voltage less than V_{dd}
 - Non-zero body bias (body effect)



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Power gating

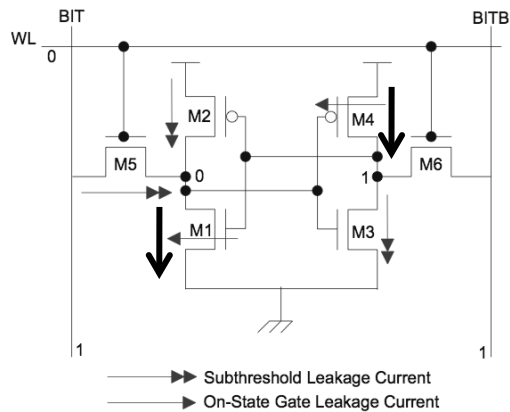


- Shut-off the power (or ground) of a unit
 - Preferably using a high V_{th} transistor
 - Safe for combinational circuits
 - State loss for sequential circuits
- Requires large power switching transistor
 - Consumes dynamic power, may cause slow down

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SRAM leakage



Gate leakage for 'on' transistors at least an order of magnitude greater

- Asymmetric, low leakage cell when storing 0 (as in fig)
 - Change M5, M2, M3 to high V_t

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Cache leakage power

- On-chip caches account for most of the “real-estate” of a chip
- Most of the cache transistors are not switching most of the time
- Two types of leakage reduction methods:
 - State-destructive, e.g. cache decay
 - State-preserving, e.g. drowsy cache

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Decay policy

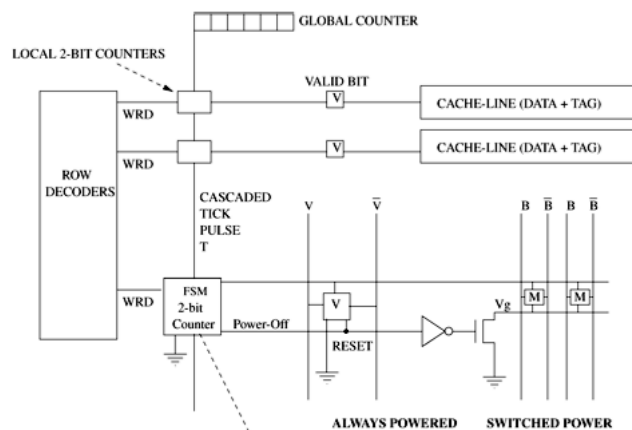
- Leave lines on for ~10K cycles from last access
 - Based on competitive algorithms
 - Switch off when leakage already dissipated equal to dyn energy of a miss
- Adaptive approaches may be better
 - Change this 10K according to application
 - Harder to implement

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Cache decay circuits

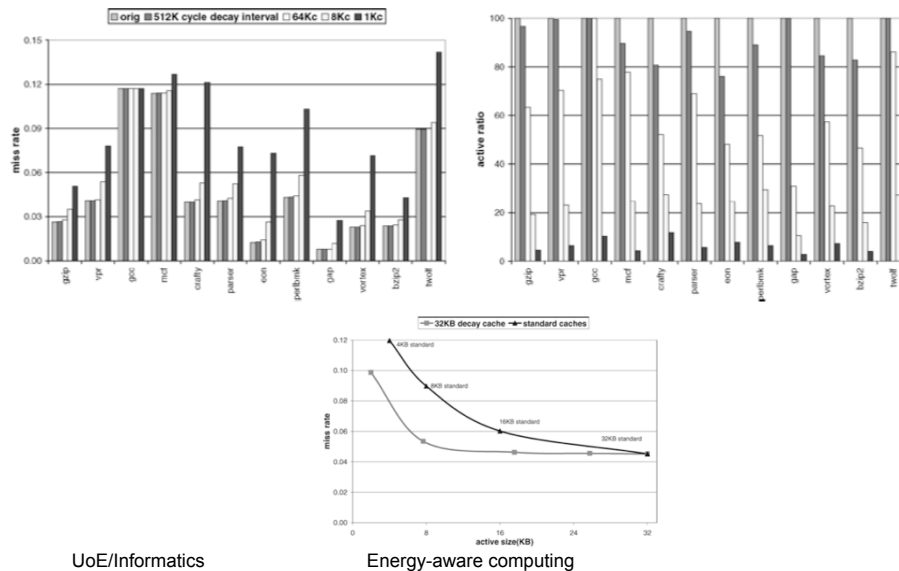
Hierarchical counter-based implementation



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Decay evaluation



Drowsy cache

- Put a “dead line” into drowsy mode
 - Line is driven at lower supply voltage
 - Around 1.5x the transistor threshold voltage
 - Leaks more than decay on bit per bit comp.
 - State is preserved but inaccessible
- Relatively quick return to normal mode
 - 1-2 cycles should be enough
 - No need for a lower level mem access

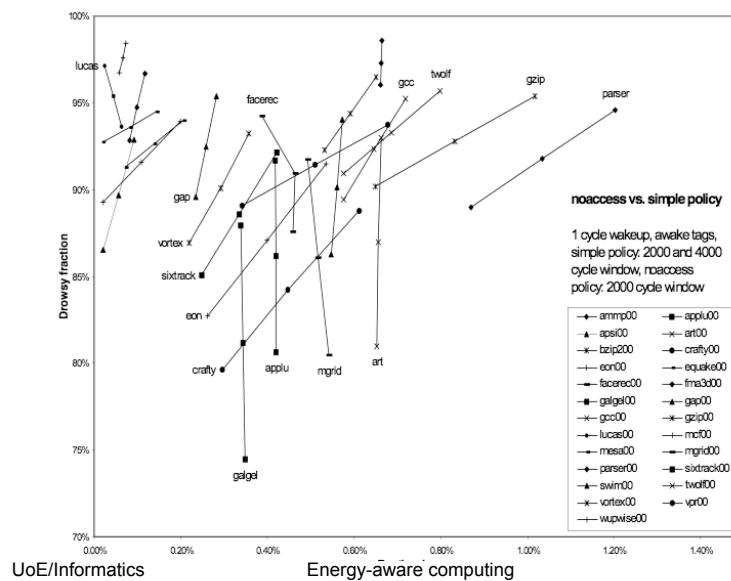
Drowsy cache policy

- Allows for simpler policies than decay
 - Cost of wrong prediction is small
- Periodically put all lines in drowsy mode (ignoring access history) and wake up when accessed
- Drowsy tags?
 - Performance penalty for drowsy tags
 - Important only for associative caches

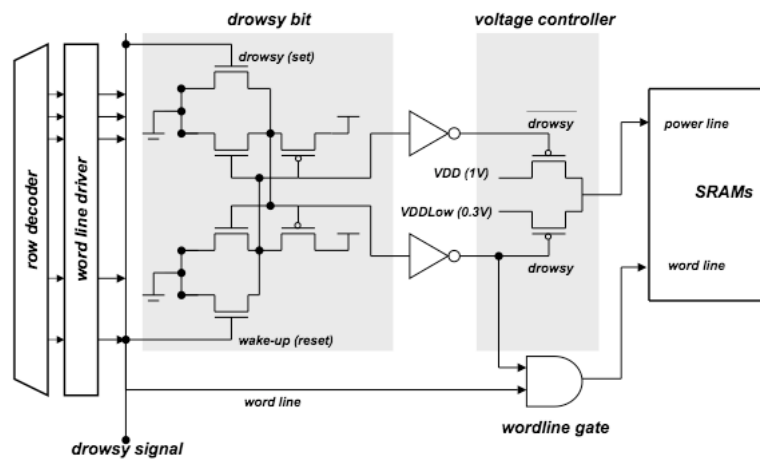
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Policy comparison



Drowsy circuits



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Drowsy energy

- Average total energy reduction 50%
- Leakage reduction 71% with active tags
 - 76% with drowsy tags
- EDP with drowsy tags always better
 - Decision based on acceptability of performance degradation

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